# **CPI Electron Device Business - Microwave Power Module**

The PTXM1057/PTXM1059 is an ultra compact modular microwave power module with an integrated "super mini" traveling wave tube (TWT), a solid state preamplifier, and an optimized high density switchmode power supply.

The PTXM1057 features a broadband (7.5 to 18 GHz) TWT capable of providing over 140 W, while the PTXM1059 provides over 110 W from 6.0 to 18.0 GHz.

A low-gain TWT is specified together with a low-noise solid state preamplifier to provide optimum noise performance.

The MPM includes a high speed focus electrode modulator to permit operation at high PRFs. This makes the MPM ideal for pulsed applications such as Electronic Countermeasure (ECM) systems and Radars.

To learn more about CPI EDB's MPM capabilities, contact CPI EDB at ElectronDevices@cpi-edb.com or call us at +44 (0)20 8573 5555



The PTXM1057/PTXM1059 is an ultra-compact modular microwave power module with an integrated "super mini" traveling wave tube (TWT).

#### FEATURES:

- PTXM1057 frequency: 7.5 18.0 GHz
- PTXM1059 frequency: 6.0 18.0 GHz
- Duty cycle: 100% max
- Weight: 5.3 lbs (2.4 kgs) max
- Pulsewidth: 0.1 to  $\infty \mu s$

#### BENEFITS

- Compact size
- Lightweight
- High electrical efficiency
- High-voltage capability
- Suitable for high-altitude operations
- Resilient in high-humidity environments

#### **APPLICATIONS:**

- Radar systems
- Electronic Countermeasure (ECM)
  systems





### **RF Characteristics**

Frequency range		See graph
RF output power		See graph
(saturated)		
Duty cycle		100% max
Small signal gain		55 dB nom
RF input power		0 ± 1 dBm
(for saturation)		
Second harmonic at s	saturation	
PTXM1057:	7.5 – 9.0 GHz:	-6 dBc
	>9 GHz:	-8 dBc
PTXM1059:	6.0 – 7.0 GHz:	-3 dBc
	8.0- 9.0 GHz:	-6 dBc
	>9 GHz:	-8 dBc
Noise power density	-24 d	Bm/MHz max
(Beam On)		
Noise power density	-75 d	Bm/MHz max
(Beam Off)		
Maximum spurious P	M -38	dBc45 dBc
measured in a 100 Hz	Z	
bandwidth Note 1		

Phase noise power de	nsity	
-100 dBc/Hz max at 1 kHz from carrier		
-110 dBc/Hz max at 10 kHz from carrier		
-120 dBc/Hz max at >100 kHz from carrier		
Noise figure	27 dB (typical)	
Input VSWR	2.0:1 max	
Output VSWR	2.0:1 max (no damage)	
Pulse width	0.1 to ∞µs (CW operation)	
Pulse delay	150 ns max	
(ON command to RF o	ut)	
Pulse repetition freque	ency 20 kHz max	
(PRF)		

## **Prime Power Requirements**

Prime power	270 V DC Per MIL-STD-704E	
	(±10% normal operating range)	
Power consumpt	ion 620 W maximum	



Connectors	
Primary power input	Glenair: MRM18396
connector	
Control and monitoring	Glenair: MRM18395
connector	
RF input connector	SMA female
RF output connector	TNC female
Control and Monitoring	
Control inputs	HV on,
	TWT beam on
Status outputs	Standby,
	HV on,
	Fault
Fault protection	
Extensive internal BIT incom	rporated to monitor
most TWT parameters. MPI	M shuts down under
fault conditions. TWT operations	ating parameters can
be monitored externally to	aid fault location.
An over-temperature trip is	s incorporated.
Fault outputs	Over-temperature
	Summary fault
TWT monitor outputs	Cathode voltage,
	Beam current,
	Helix current
Heater warmup 180 S	econds from power on
Automatic restart	Auto-reset after fault
	is included (3 restarts)

Mechanical		
Mechanical outline	e	
	254	.0 x 135.0 x 45.5 mm
e>	excluding fixings and connector	
254.0 x 15	5.0 x 45.5 n	nm including fixings
Mechanical outline	e drawing	1V020806
Weight		5.3 lbs (2.4 kgs) max
Orientation		Any
Finish		Nickel plated
Markings/Labels		Type number
		Model number
		Serial number
		Connector ident
		Hazard warning
Cooling	Condu	uction via baseplate,
	+71 °C ma	ximum temperature

### **Options (available on request)**

Alternative prime power 28 V, 115 VAC 3-phase (plug-in or stand-alone converters)

### Environmental

Temperature (operating	) -40 °C to + 71 °C
Ambient temperature	-54 °C to + 100 °C
storage)	
Baseplate temperature	+71 °C maximum
(MPM)	(operating)
Altitude (operating)	0 - 40,000 ft
Vibration	0.2 g²/Hz 10 to 40 Hz
(operating - 3 axes)	0.04 g <sup>2</sup> /Hz 40 to 2000 Hz



Shock (3 axes)		40 g, 6 ms half sine
Humidity (condensir	ıg)	MIL-STD-810D
	Metho	od 507.2 procedure II
EMC performance		MIL-STD-461E
	Require	es external EMC filter

Notes:

1 Lower spurious values are achievable for close to carrier noise using sync or pre-trigger function



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